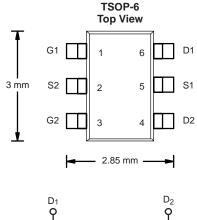
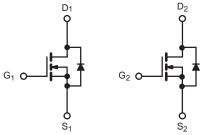


## DMN5L06DMK-7-VB Datasheet Dual N-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}$ ( $\Omega$ )	I <sub>D</sub> (mA)		
60	1.8 at V <sub>GS</sub> = 10 V	350		



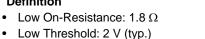


N-Channel MOSFET

N-Channel MOSFET

#### **FEATURES**

 Halogen-free According to IEC 61249-2-21 Definition



Low Input Capacitance: 30 pFFast Switching Speed: 25 ns

Low Input and Output Leakage

Trench Power MOSFET

Compliant to RoHS Directive 2002/95/EC

# Pb-free Available

RoHS\*

FREE Available

#### **BENEFITS**

- Low Offset Voltage
- Low-Voltage Operation
- · Easily Driven Without Buffer
- · High-Speed Circuits
- Low Error Voltage

#### **APPLICATIONS**

- Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers, Display, Memories, Transistors, etc.
- · Battery Operated Systems
- Solid-State Relays

<b>ABSOLUTE MAXIMUM RATINGS</b> T <sub>A</sub> = 25 °C, unless otherwise noted					
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V <sub>DS</sub>	60		
Gate-Source Voltage		$V_{GS}$	± 20	V	
Continuous Proje Compact /T 450 9CVb	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	350	mA	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>b</sup>	T <sub>A</sub> = 100 °C		230		
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	900		
Devices Discipation b	T <sub>A</sub> = 25 °C	- P <sub>D</sub>	0.45	- W	
Power Dissipation <sup>b</sup>	T <sub>A</sub> = 100 °C		0.24		
Maximum Junction-to-Ambient <sup>b</sup>		R <sub>thJA</sub>	350	°C/W	
Operating Junction and Storage Temperature Range		T <sub>J,</sub> T <sub>stg</sub>	- 55 to 150	°C	

#### Notes:

- a. Pulse width limited by maximum junction temperature.
- b. Surface Mounted on FR4 board.

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<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply.



			Limits			
Parameter	Symbol	Symbol Test Conditions		Min. Typ. <sup>a</sup> Max.		Unit
Static			•			
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 \text{ V}, I_D = 10 \mu\text{A}$	60			V
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1		2.5	
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 10	^
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 15 \text{ V}$			1	μA
Gate-Body Leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ± 10 V			± 150	nA
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			± 1000	
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 5 \text{ V}$			± 100	
Zana Cata Malta na Duain Comunit	1	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V			1	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V , T <sub>J</sub> = 125 °C	60 V, V <sub>GS</sub> = 0 V , T <sub>J</sub> = 125 °C		500	μA
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{GS} = 10 \text{ V}, V_{DS} = 7.5 \text{ V}$	800			
		$V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V}$	500			mA
	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 500 \text{ mA}$		1.8		Ω
Drain-Source On-Resistance <sup>a</sup>		$V_{GS} = 4.5 \text{ V}, I_D = 200 \text{ mA}$		3		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 200 mA	100			mS
Diode Forward Voltage	V <sub>SD</sub>	$I_S = 200 \text{ mA}, V_{GS} = 0 \text{ V}$			1.3	V
Dynamic <sup>a</sup>			1	1		
Total Gate Charge	Qg	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}$ $I_{D} \cong 250 \text{ mA}$		0.6	0.8	nC
Input Capacitance	C <sub>iss</sub>			30		pF
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}$ $f = 1 \text{ MHz}$		6		
Reverse Transfer Capacitance	C <sub>rss</sub>	T = T IVIMZ		2.5		
Switching <sup>a, b, c</sup>	•					
Turn-On Time	t <sub>d(on)</sub>	$V_{DD} = 30 \text{ V}, R_{L} = 150 \Omega$			25	
Turn-Off Time	t <sub>d(off)</sub>	$I_{\rm D} \cong 200  {\rm mA},  {\rm V}_{\rm GEN} = 10  {\rm V},  {\rm R}_{\rm G} = 10  {\rm \Omega}$			35	ns

#### Notes:

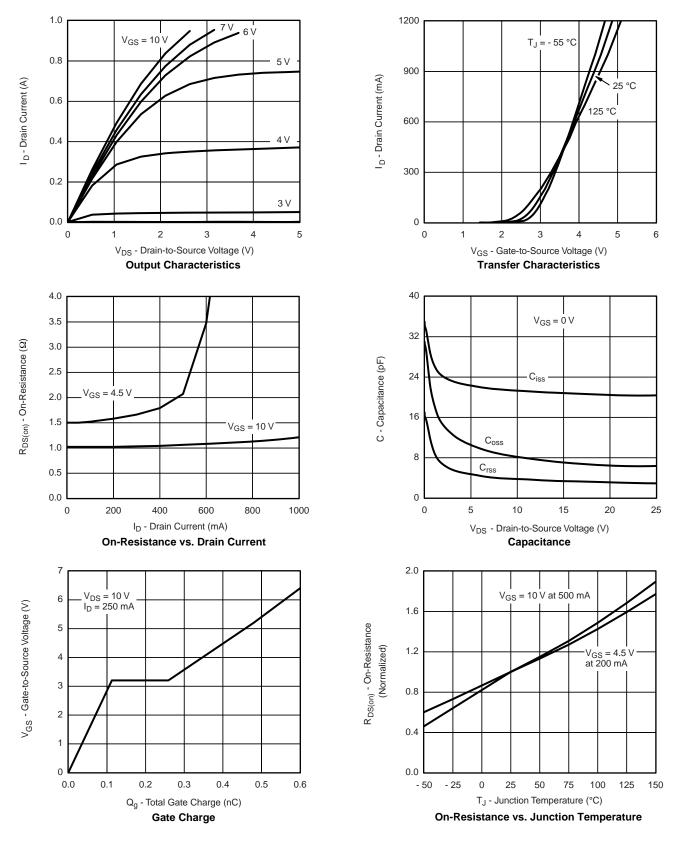
- a. For DESIGN AID ONLY, not subject to production testing.
- b. Pulse test: PW  $\leq$  300  $\mu s$  duty cycle  $\leq$  2 %.
- c. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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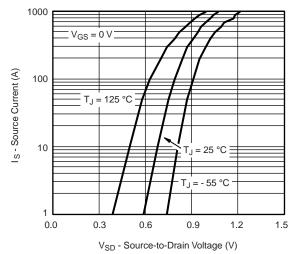


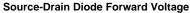
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

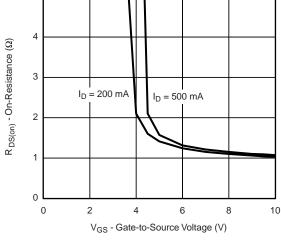




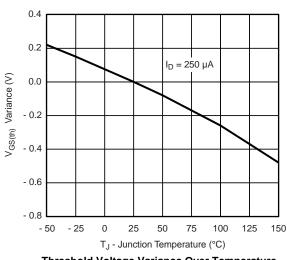
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



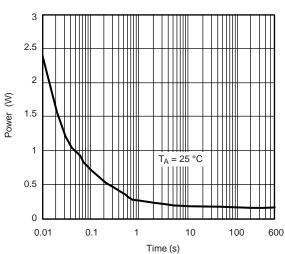




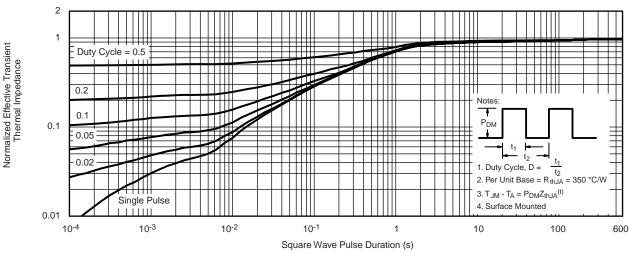
On-Resistance vs. Gate-Source Voltage



**Threshold Voltage Variance Over Temperature** 



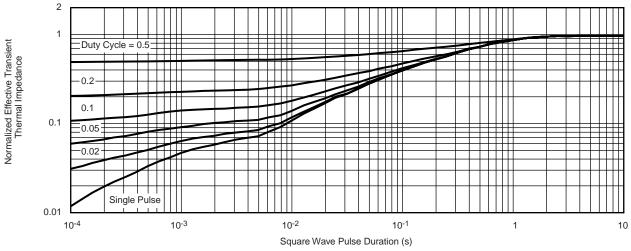
Single Pulse Power, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient



#### **THERMAL RATINGS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



#### Normalized Thermal Transient Impedance, Junction-to-Foot

#### Note

- · The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Foot (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

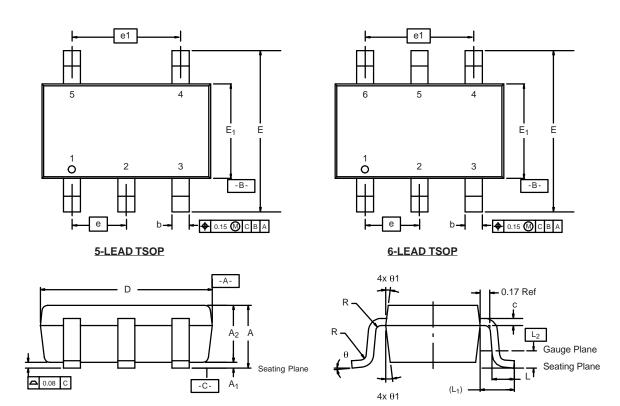
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5



TSOP: 5/6-LEAD

**JEDEC Part Number: MO-193C** 

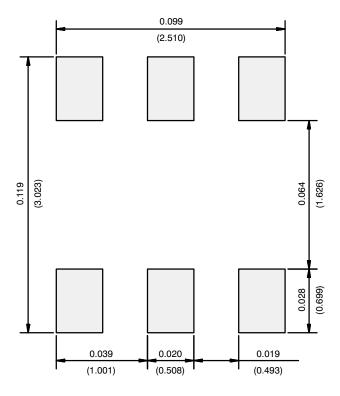


	MILLIMETERS			INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A <sub>1</sub>	0.01	-	0.10	0.0004	-	0.004	
A <sub>2</sub>	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
Е	2.70	2.85	2.98	0.106	0.112	0.117	
E <sub>1</sub>	1.55	1.65	1.70	0.061	0.065	0.067	
е	0.95 BSC			0.0374 BSC			
e <sub>1</sub>	1.80	1.90	2.00	0.071	0.075	0.079	
L	0.32	-	0.50	0.012	-	0.020	
L <sub>1</sub>	0.60 Ref			0.024 Ref			
L <sub>2</sub>	0.25 BSC			0.010 BSC			
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
$\theta_1$		7° Nom 7° Nom			•		
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							

DWG: 5540



#### **RECOMMENDED MINIMUM PADS FOR TSOP-6**



Recommended Minimum Pads Dimensions in Inches/(mm)

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